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## CORRECTION

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## Correction: Electronic structure of the boron fullerene B<sub>14</sub> and its silicon derivatives B<sub>13</sub>Si<sup>+</sup>, B<sub>13</sub>Si<sup>-</sup> and B<sub>12</sub>Si<sub>2</sub>: a rationalization using a cylinder model

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Correction for 'Electronic structure of the boron fullerene  $B_{14}$  and its silicon derivatives  $B_{13}Si^+$ ,  $B_{13}Si^-$  and  $B_{12}Si_2$ : a rationalization using a cylinder model' by Long Van Duong et al., Phys. Chem. Chem. Phys., 2016, **18**, 17619–17626.

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The authors would like to amend some of the affiliation details in their article. The correct information can be found here.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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